

L Number	Hits	Search Text	DB	Time stamp
1	755	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and semiconductor.as.	USPAT; US-PGPUB; JPO	2003/11/06 17:40
2	672	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as.	USPAT; US-PGPUB; JPO	2003/11/06 17:41
4	0	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and 349/\$.ccls.	USOCR	2003/11/06 17:41
3	139	(liquid adj crystal) and (conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and 349/\$.ccls.	USPAT; US-PGPUB; JPO	2003/11/06 17:48
5	140	(conduct\$ or dummy)and seal\$4 and insulat\$5 and semiconductor.as. and 349/\$.ccls.	USPAT; US-PGPUB; JPO	2003/11/06 17:49
6	89	(conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4 and insulat\$5 and semiconductor.as. and 349/\$.ccls.	USPAT; US-PGPUB; JPO	2003/11/06 17:51
7	5	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and semiconductor.as. and 349/\$.ccls.	USPAT; US-PGPUB; JPO	2003/11/06 17:55
8	79	((conduct\$ or dummy)and (gate or scan\$4)and (data or signal)and seal\$4) near10 insulat\$5 and 349/\$.ccls.	USPAT; US-PGPUB; JPO	2003/11/06 17:56
-	136	349/190	USPAT	2003/11/06 15:07
-	321	349/155	USPAT	2001/07/25 08:40
-	444	349/149	USPAT	2001/07/25 08:40
-	176	349/151	USPAT	2001/07/25 08:40
-	309	345/206	USPAT	2001/07/25 08:42
-	2	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	2002/05/13 09:43
-	0	349/190 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	2001/07/25 08:49
-	223	349/153 and (conduct\$ or dummy)	USPAT	2001/07/25 08:51
-	130	349/153 and (conduct\$ or dummy)and insulat\$	USPAT	2001/07/25 08:53
-	15	349/190 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	2001/07/25 08:55
-	54	349/155 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	2001/07/25 08:56
-	88	349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	2001/07/25 08:57
-	5	349/149 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	2001/07/25 08:58
-	5	349/151 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	2001/07/25 08:59
-	3	345/206 and (conduct\$ or dummy)and insulat\$ and overlap\$ and (top adj gate)	USPAT	2001/07/25 09:00
-	53	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT	2003/04/25 10:07
-	298	349/153	USPAT	2001/07/26 08:15
-	1	5995189.pn.	USPAT	2002/02/25 10:05
-	4	349/153 and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	2002/05/13 10:06
-	407	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$	USPAT	2002/05/13 10:16
-	125	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4	USPAT	2002/05/13 12:53
-	33	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	USPAT	2003/11/06 17:39
-	165	(liquid adj crystal) and (conduct\$ or dummy)and (top adj gate) and crystal\$ and seal\$4 and semiconductor.as.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/25 09:48
-	96	349/153 and (conduct\$ or dummy)and insulat\$ and overlap\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/25 10:16

-	6	349/153 and 349/141	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/25 10:39
-	1	JP02214934.ap.	JPO	2003/11/06 15:09
-	1	JP04219642.ap.	JPO	2003/11/06 16:10